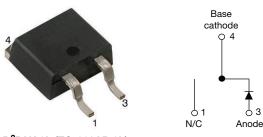


# 650 V Gen 3 Power SiC Merged PIN Schottky Diode, 12 A



D<sup>2</sup>PAK 2L (TO-263AB 2L)

### **LINKS TO ADDITIONAL RESOURCES**

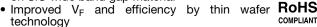




PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	12 A					
V <sub>R</sub>	650 V					
V <sub>F</sub> at I <sub>F</sub> at 25 °C,typ.	1.3 V					
T <sub>J</sub> max.	175 °C					
I <sub>R</sub> at V <sub>R</sub> at 175 °C	5 μΑ					
Q <sub>C</sub> (V <sub>R</sub> = 400 V)	34 nC					
Package	D <sup>2</sup> PAK 2L (TO-263AB 2L)					
Circuit configuration	Single					

#### **FEATURES**

· Majority carrier diode using Schottky technology on SiC wide band gap material



COMPLIANT HALOGEN

**FREE** 

 Positive V<sub>F</sub> temperature coefficient for easy paralleling

- Virtually no recovery tail and no switching losses
- Temperature invariant switching behavior
- 175 °C maximum operating junction temperature
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- · MPS structure for high ruggedness to forward current surge events
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION / APPLICATIONS**

Wide band gap SiC based 650 V Schottky diode, designed for high performance and ruggedness.

Optimum choice for high speed hard switching and efficient operation over a wide temperature range, it is also recommended for all applications suffering from Silicon ultrafast recovery behavior.

Typical applications include AC/DC PFC and DC/DC ultra high frequency output rectification in FBPS and LLC converters.

#### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		650	V		
Continuous forward current	I <sub>F</sub> <sup>(1)</sup>	$T_C = 135  ^{\circ}C  (DC)$	12	_		
Continuous forward current	I <sub>F</sub> <sup>(2)</sup>	$T_C = 145 ^{\circ}C (DC)$	12	Α		
DC blocking voltage	$V_{DC}$		650	V		
Repetitive peak forward current I		$T_C$ = 25 °C, f = 50 Hz, square wave, DC = 25 %	48			
Non repetitive peak forward aurae aurant	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 10$ ms, half sine wave	83	A		
Non-repetitive peak forward surge current		$T_C = 110  ^{\circ}\text{C}$ , $t_p = 10  \text{ms}$ , half sine wave	74			
	P <sub>tot</sub> (1)	T <sub>C</sub> = 25 °C	73	W		
Power dissipation	Ftot ('')	T <sub>C</sub> = 110 °C	32	VV		
Fower dissipation	D (2)	$T_C = 25  ^{\circ}C$	94	14/		
	P <sub>tot</sub> (2)	T <sub>C</sub> = 110 °C	40	W		
10.	∫i <sup>2</sup> dt	T <sub>C</sub> = 25 °C	34.5	42-		
l <sup>2</sup> t value	Ji at	T <sub>C</sub> = 110 °C	27	A <sup>2</sup> s		
Operating junction and storage temperatures	T <sub>J</sub> <sup>(2)</sup> , T <sub>Stg</sub>		-55 to +175	°C		

## **Notes**

- (1) Based on maximum Rth
- (2) Based on typical Rth
- (3) The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>B,IA</sub>



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS	
		I <sub>F</sub> = 12 A	-	1.3	1.5		
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 12 A, T <sub>J</sub> = 150 °C	-	1.50	1.85	V	
		I <sub>F</sub> = 12 A, T <sub>J</sub> = 175 °C	-	1.58	-		
Reverse leakage current	I <sub>R</sub>	$V_R = V_R$ rated	-	0.8	65	μА	
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 150 °C	-	3	150		
		V <sub>R</sub> = V <sub>R</sub> rated, T <sub>J</sub> = 175 °C	-	5	-		
Total capacitance	С	V <sub>R</sub> = 1 V, f = 1 MHz	-	535		pF	
		V <sub>R</sub> = 400 V, f = 1 MHz	-	54	-	PΓ	
Total capacitive charge	Q <sub>C</sub>	V <sub>R</sub> = 400 V, f = 1 MHz	-	34	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS (T <sub>A</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS						
Thermal resistance, junction to case	R <sub>thJC</sub>		-	1.6	2.1	°C/W	
Marking device	3C12ET07S						

1000

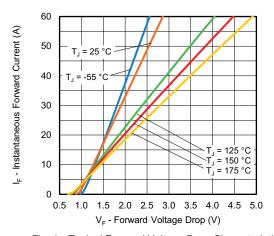


Fig. 1 - Typical Forward Voltage Drop Characteristics

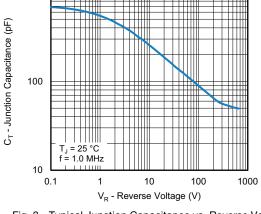


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

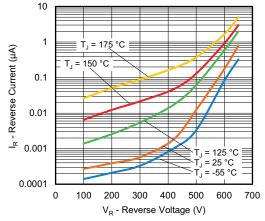


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

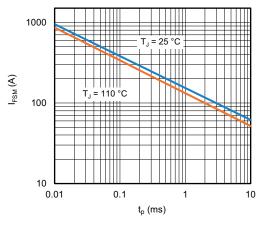


Fig. 4 - Non-Repetitive Peak Forward Surge Current vs. Pulse Duration (Square Wave)



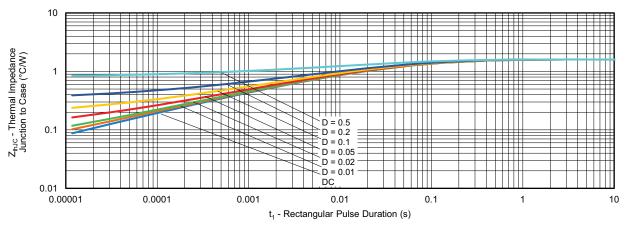


Fig. 5 - Typical Thermal Impedance  $Z_{thJC}$  Characteristics

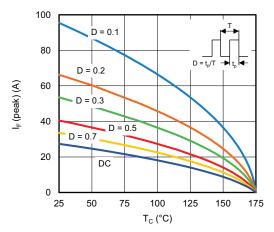


Fig. 6 - Peak Forward Current vs. Maximum Allowable Case Temperature

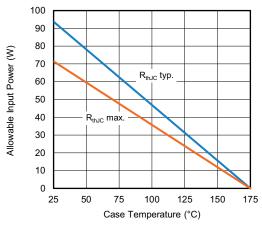


Fig. 7 - Forward Power Loss Characteristics

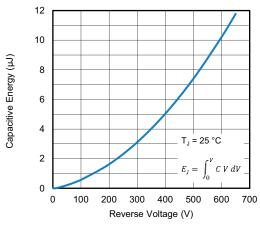


Fig. 8 - Typical Capacitive Energy vs. Reverse Voltage

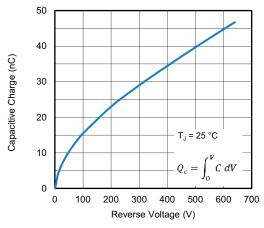
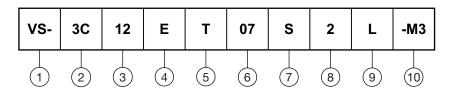


Fig. 9 - Typical Capacitive Charge vs. Reverse Voltage

## **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

- 3C = SiC diode, generation 3

**3** - Current rating (12 = 12 A)

4 - E = single diode

T = D<sup>2</sup>PAK package

6 - Voltage rating: (07 = 650 V)

- S = surface mountable

9 - L = tape and reel (left oriented)

10 - Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

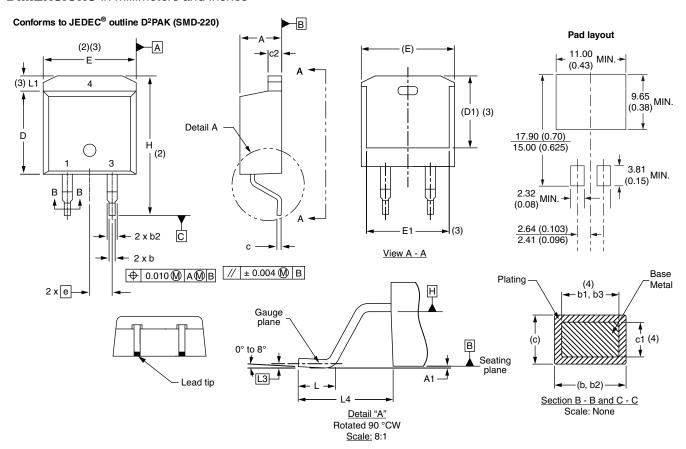
ORDERING INFORMATION					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-3C12ET07S2L-M3	800 per reel	13" diameter reel			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?96683			
Part marking information	www.vishay.com/doc?96693			
Packaging information	www.vishay.com/doc?95032			



# **D<sup>2</sup>PAK 2L (TO-263AB 2L)**

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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